

Published on Web 08/11/2006

Very Large Changes in Bond Length and Bond Angle in a Heavy Group 14 Element Alkyne Analogue by Modification of a Remote Ligand Substituent

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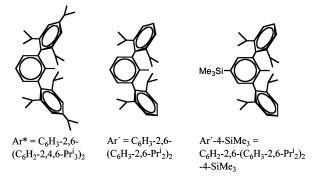
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Recent experimental work^{1–8} has resulted in the syntheses and structural characterization of several examples of stable heavier group 14 element alkyne analogues of formula RMMR (R = large aryl or silyl substituent, M = Si, Ge, Sn, Pb). X-ray crystallographic studies have shown that they have a *trans*-bent, planar, ^{1–3,7} or almost planar⁸ core arrangement with angles at M that range from 137.44-(4)° (M = Si)⁷ to 94.26(4)° (M = Pb).¹ With the exception of the lead derivative, the M–M distances fall in the range expected for an M–M bond order between 2 and 3. For the lead species Ar*PbPbAr* (Ar* = C₆H₃-2,6-(C₆H₂-2,4,6-*i*-Pr₃)₂, Scheme 1), the Pb–Pb bond length is 3.1881(1) Å and there is a strongly bent (Pb–Pb–C = 94.26(4)°) core structure consistent with the representation

in which there is single-bonding and a nonbonding pairs of electrons at each lead. Calculations by Frenking and co-workers have shown that the Ar* ligand plays a crucial role in stabilizing the observed molecular configuration in comparison to others that would be more stable (by <10 kcal mol⁻¹) with less crowding ligands. ⁹ Calculations by Nagase and Takagi¹⁰ for the Ge and Sn species RMMR (R = Ar* or Tbt (Tbt = C_6H_2 -2,4,6-{CH(SiMe₃)₂}₃) predicted structures for Ar*GeGeAr* (Ge-Ge = 2.277 Å, Ge-Ge-C = 123.2°)¹¹ and TbtGeGeTbt (Ge-Ge = 2.231 Å, Ge-Ge-C = 121.8°) that were quite similar to those experimentally measured for Ar'GeGeAr' (Ar' $= C_6H_3-2,6-(C_6H_3-2,6-i-Pr_2)_2^3$, Ge-Ge = 2.2850(6) Å, Ge-Ge-C = 128.27(8)°) and more recently by Tokitoh and co-workers for BbtGeGeBbt (Bbt = $C_6H_2-2,6-\{CH(SiMe_3)_2\}_2-4-C(SiMe_3)_3$, Ge-Ge = 2.22 Å avg, $Ge-Ge-C = 131^{\circ} \text{ avg}$). These bond distances were in the range observed for the Ge-Ge double bonds in digermenes.12 The stronger bonding in BbtGeGeBbt was rationalized on the basis of a lower Δ_{D-O} for the GeBbt fragment, which leads to a stronger Ge-Ge interaction. 8 In contrast, the calculations predicted that a "multiple-bonded" Ar*SnSnAr* should have a more trans-bent structure (Sn-Sn-C = 111.0° , a C-Sn-Sn-C torsion angle of 125.3°) and a relatively long Sn-Sn bond of 2.900 Å. These values differed considerably from those experimentally measured for Ar'SnSnAr' (Sn-Sn = 2.6675(4) Å, Sn-Sn-C = 125.249(2)°). The calculations also predicted that the singly-bonded Ar*SnSnAr* isomer (analogous to the Ar*PbPbAr* structure above) with Sn-Sn = 3.087 Å and $Sn-Sn-C = 99.0^{\circ}$ differed in energy by only 4.8 kcal mol⁻¹ from "multiple-bonded" Ar*SnSnAr*. Seemingly, these large structural changes carry only a small energy

Scheme 1. Schematic Drawing of Ar*, Ar', and Ar'-4-SiMe₃



Scheme 2. Synthetic Routes to 1-4

$$1-\text{Li-2,6-Cl}_2-\text{C}_6\text{H}_2-4-\text{SiMe}_3 \xrightarrow{2) \text{I}_2} 1-\text{I-Ar'-4-SiMe}_3 \xrightarrow{4 \text{ LiBu}^n} \\ \text{I-ClSn-Ar'-4-SiMe}_3 \text{I}_2 \xrightarrow{\text{SnCl}_2} [1-\text{Li-Ar'-4-SiMe}_3]_2 \xrightarrow{4-\text{SiMe}_3-\text{Ar'SnSnAr'-4-SiMe}_3}$$

penalty, and this unusual result has been confirmed by calculations on simpler RMMR (M = Si-Pb; $R = H^{13}$ or Me^{14}) models.

We now supply experimental evidence to support this prediction by the synthesis and characterization of the alkyne analogue 4-Me₃-Si-Ar'SnSnAr'-4-SiMe₃ (1). This compound employs the modified terphenyl ligand C_6H_2 -2,6-(C_6H_3 -2,6-i-Pr₂)₂-4-SiMe₃ (Ar'-4-SiMe₃, Scheme 1) in place of Ar'. This results in a species that has a much longer Sn-Sn distance and a narrower Sn-Sn-C angle than those found in Ar'SnSnAr'.

The ligand precursor 1-I-C₆H₂-2,6-(C₆H₃-2,6-*i*-Pr₂)₂-4-SiMe₃ (**4**) was isolated by the addition of 2 equiv of BrMgC₆H₃-2,6-*i*-Pr₂ (BrMgDipp) to 1-Li-2,6-Cl₂-C₆H₂-4-SiMe₃, with subsequent quenching with I₂ by a standard route¹⁵ (Scheme 2). In a manner similar to the preparation of [Ar'Li]₂, ¹⁶ **3** was synthesized by reaction of **4** with *n*-BuLi.

Subsequent reaction of **3** with excess $SnCl_2$ in diethyl ether and crystallization from the same solvent at -20 °C yielded [1-ClSnC₆H₂-2,6-(C₆H₃-2,6-*i*-Pr₂)₂-4-SiMe₃]₂ (**2**). Reduction of **2** with potassium in diethyl ether and subsequent crystallization afforded **1** as dark green, air- and moisture-sensitive crystals. The X-ray crystallography showed that **1** has a *trans*-bent structure in the solid state with geometric (Figure 1) parameters that differ dramatically (Figure 2) from those previously reported for Ar'SnSnAr'.

In 1, the Sn—Sn bond length is 3.066(1) Å, which is about 0.4 Å longer than the 2.6675(4) Å in Ar'SnSnAr'. In addition, the Sn—

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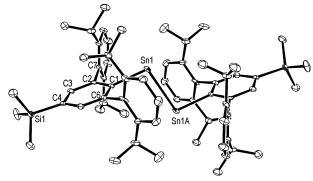


Figure 1. Thermal ellipsoidal plot of 1 (30% probability) without H atoms. Selected bond distances (Å) and angles (°): Sn(1)-Sn(1a), 3.066(1); Sn-(1)-C(1), 2.208(5); Si(1)-C(4), 1.878(6); C(1)-Sn(1)-Sn(1a), 99.25(14); C(2)-C(1)-Sn(1), 125.6(4); C(6)-C(1)-Sn(1), 115.0(4); C(2)-C(1)-Sn(1), 115.0(4); C(2)-C(1)-Sn(1)-Sn(1), 115.0(4); C(2)-C(1)-Sn(C(6), 118.3(5); C(1)-C(2)-C(7), 121.6(5); C(3)-C(2)-C(7), 118.5(5).

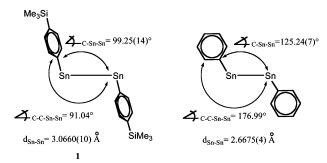


Figure 2. Comparison of core geometries for 4-SiMe₃Ar'SnSnAr'-4-SiMe₃ 1 and Ar'SnSnAr', flanking aryl groups are not shown for clarity.

Sn-C bond angle is 99.25(14)°, a decrease of about 26° in comparison to the 125.24(7)° in Ar'SnSnAr'. Hence, the structural parameters resemble those of Ar*PbPbAr* (Pb-Pb = 3.1881(1))Å, $Pb-Pb-C = 94.26(4)^{\circ}$) more than those of Ar'SnSnAr' and are consistent with Sn-Sn single bonding. Another striking difference between the solid-state structures of 1 and Ar'SnSnAr' is the perpendicular arrangement of the ligand's central aryl rings relative to the C-Sn-Sn-C in contrast to the parallel orientation in Ar'SnSnAr', where the central aryl rings lie in the plane with the central structural unit. The dihedral angles Sn-Sn-C-C in 1 are 91.04 and -101.08°, but are 176.99° and 3.09° in Ar'SnSnAr', whereas the lead derivative Ar*PbPbAr* exhibits torsional angles of 95.16° and -88.98°.

The UV-vis spectrum of 1 in hexanes displays two strong absorptions at 416 ($\epsilon = 4700 \text{ L mol}^{-1} \text{ cm}^{-1}$) and 608 ($\epsilon = 1200 \text{ L}$ mol ⁻¹ cm⁻¹) nm and are slightly bathochromically shifted in comparison to those of Ar'SnSnAr' (410 and 597 nm) and Ar*SnSnAr* (409 and 593 nm), suggesting similar, strongly bent structures of the three compounds in solution.

Our results vindicate the theoretical prediction 10,13,14 that relatively small amounts of energy separate two different bonding modes of the tin analogues of alkynes. Modification of the known terphenyl ligand Ar' by the introduction of SiMe₃ instead of H at the paraposition of the central aryl ring induces a single-bonded structure without alteration of the steric crowding near the tin center. Preliminary theoretical data on model moieties MC₆H₄-4-SiMe₃ and MC_6H_5 (M = Ge, Sn) indicate about a 2 kcal mol⁻¹ difference in their Δ_{D-Q} energies that, when added together in the dimerized product, results in a 4 kcal mol⁻¹ difference. ¹⁹ However it should be borne in mind that these energy differences are sufficiently small to be in the range of packing forces.

Acknowledgment. We are grateful to the National Science Foundation for financial support. R.C.F. thanks the Max Kade foundation for a postdoctoral fellowship.

Supporting Information Available: X-ray data (CIF) for 1. This material is available free of charge via the Internet at http://www.pubs.acs.org.

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- (17) At room temperature and under strictly anhydrous and anaerobic conditions, a solution of 0.850 g (1.36 mmol) [1-ClSn-C₆H₂-2,6-(C₆H₃-2,6-i-Pr₂)₂-4-SiMe₃]₂ (prepared in a fashion similar to previously reported procedures)⁵ in diethyl ether (25 mL) was added to a diethyl ether suspension of 0.059 g (1.51 mmol) of finely dispersed potassium with rapid stirring. The reaction mixture quickly adopted a deep green color, and stirring was continued for 24 h, after which the precipitated material and unreacted potassium were allowed to settle. The solution was filtered through a filter-tipped cannula and concentrated in vacuo to incipient crystallization (ca. 10 mL). Storage at $-20\,^{\circ}$ C yielded 0.41 g (0.328 mmol, 48% yield) of dichroic green-dark orange crystals of $1 \cdot \text{Et}_2\text{O}$. Anal. Calcd for $1 \cdot \text{Et}_2\text{O}$ C₇₀H₁₀₀OSi₂Sn₂: C, 67.20; H, 8.06. Found: C, 66.79; H, 8.22. for $\Gamma \cdot Et_2 O C_{70} H_{100} OS_{12} Sn_2$: C, $6I \cdot 20$; H, 8.06. Found: C, 66.79; H, 8.22. Mp 183 - 185 dec. $UV - vis \lambda_{max}$ (nm, ϵ [L mol $^{-1}$ cm $^{-1}$]): 416 (4700), 608 (1200). 1 H NMR ($C_6 D_6$, 599.814 MHz, 25 $^{\circ}$ C): -0.28 (s, 18H, $(CH_3)_3 Si)$, 1.12 (t, 6H, $(CH_3 CH_2)_2 O$), 1.16 (d, 24H, $^{3}I_{HH} = 6.8$ Hz, o-CH-(CH_3)(CH_3)), 1.38 (d, 24H, $^{3}I_{HH} = 6.8$ Hz, o-CH(CH_3)(CH_3)), 2.94 (septet SH, $^{3}I_{HH} = 6.8$ Hz, o-CH(CH_3)(CH_3)), 3.27 (q, 4H, ($CH_3 CH_2 D_2 O$), 7.07 (d, 8H, $^{3}I_{HH} = 6.7$ Hz, p-Dipp), 7.17 (t, 4H, $^{3}I_{HH} = 6.7$ Hz, p-Dipp), 7.98 (s, 4H, m-C₆H₂Si(CH₃)), 13 C{1H}} ($C_6 D_6$, 150.823 MHz, 25 $^{\circ}$ C): -0.6 (($H_3 C C_3$)3Si), 15.5 (($CH_3 C C_2 C_2$), 26.9 (CH(CH_3)(CH_3)), 32.5 (CH-(CH_3)(CH_3)), 35.9 (CH(CH_3)(CH_3)), 35.9 (CH_3) (CH₃)(CH₃)), 35.9 (CH(CH₃)(CH₃)), 65.9 ((CH₄CH₂)₂O), 125.2 (pr-Dipp), 127.9 (m-Dipp), 138.0 (m-C₆H₂), 141.2 (o-Dipp), 143.2 (p-C₆H₂), 151.1 (i-Dipp), 161.4 (o-C₆H₂), 174.6 (i-C₆H₂). 29 Si{ 1 H} (C₆D₆, 119.165 MHz, 25 °C): -4.2. 119 Sn{ 1 H} (C₆D₆, 223.671 MHz, 25 °C): no signal observed.
- (18) Crystal data for $1 \cdot \text{Et}_2\text{O}$ at 90 K with Mo K α ($\lambda = 0.71073$ Å): a = 11.605(3) Å, b = 24.573(5) Å, c = 12.733(3) Å, $\beta = 114.407(4)^\circ$, V = 3306.5(12) Å³, M = 1251.06 g mol⁻¹, $\beta_{\text{calcd}} = 1.257$ Mg m⁻³, F(000) = 1312, monoclinic, space group P2(1)/c, Z = 2, R1 = 0.0557 for 3272 (I > 2(I)) data, wR2 = 0.1246 for all 5975 data. Equipment: Bruker SMART1000 CCD system. Absorption correction was performed using SADABS. 18a The structure was solved by direct methods (SHELXS-97), and nonhydrogen atoms were refined anisotropically (full-matrix least-squares on F^2 , SHELXL-97). (a) Sheldrick G. M. SADABS, version 2.10; Universität Göttingen: Göttingen, Germany, 2003. (b) Sheldrick, G. M. Acta Crystallogr. 1990, A46, 467. (c) Sheldrick, G. M. SHELXS-97 and SHELXL-97; Universität Göttingen: Göttingen, Germany, 1997. (19) Brynda, M. A.; Fischer, R. C.; Power, P. P. Unpublished work.

JA0637090